

3 A MOLD TRIAC

DESCRIPTION

The AC03DJM and AC03FJM are all diffused mold type TRIAC granted RMS On-state current 3 Amps, with rated voltage up to 600 volts.

FEATURES

- Small and surface mount package.
- 30 A Surge Current
- Less holding current distribution provides free application design.

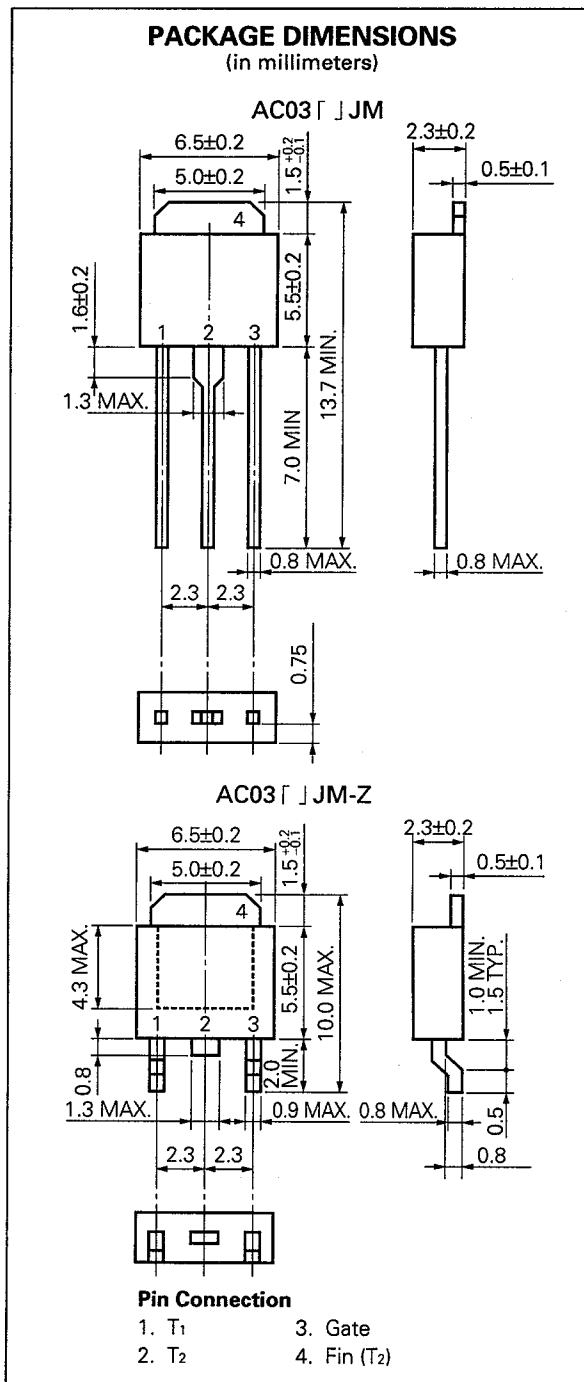
QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

APPLICATIONS

Temperature Control, Light Dimmer Control, AC Motor Speed, Control Electric Jar, Electric Lamp Starter, Various Solid State Switch, etc.



ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	AC03DJM	AC03FJM	UNIT	NOTE
Repetitive Peak Off-State Voltage	V _{DRM}	400	600	V	
Non-repetitive Peak Off-State Voltage	V _{DSM}	500	700	V	
RMS On-State Current	I _{T(RMS)}	3 (T _c = 110 °C)		A	See Fig. 11
Surge On-State Current	I _{TSM}	30 (50 Hz 1 cycle)		A	See Fig. 2
Fusing Current	$\int i^2 dt$	4.0 (1 ms ≤ t ≤ 10 ms)		A ² s	
Peak Gate Power Dissipation	P _{GM}	3 (f ≥ 50 Hz, Duty ≤ 10 %)		W	
Average Gate Power Dissipation	P _{G(AV)}	0.3		W	
Peak Gate Current	I _{GM}	±0.5 (f ≥ 50 Hz, Duty ≤ 10 %)		A	
Junction Temperature	T _j	-40 to +125		°C	
Storage Temperature	T _{stg}	-55 to +150		°C	

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	NOTE	
Peak Off-State Current	I _{DRM}	V _{DM} = V _{DRM}	-	-	100	μA		
Peak Off-State Current	I _{DRM}	T _j = 125 °C, V _{DM} = V _{DRM}	-	-	1	mA		
On-State Voltage	V _{TM}	I _{TM} = 5 A	-	-	1.8	V	See Fig. 1	
Gate-trigger Current	Trigger Mode I	V _{DM} = 12 V, R _L = 30 Ω	T ₂ +, G+	-	-	12	mA	See Fig. 4, 5, 7
	II		T ₂ -, G+	-	-	-		
	III		T ₂ -, G-	-	-	12		
	IV		T ₂ +, G-	-	-	12		
Gate-trigger Voltage	Trigger Mode I	V _{DM} = 12 V, R _L = 30 Ω	T ₂ +, G+	-	-	1.5	V	See Fig. 4, 6, 8
	II		T ₂ -, G+	-	-	-		
	III		T ₂ -, G-	-	-	1.5		
	IV		T ₂ +, G-	-	-	1.5		
Gate Non-Trigger Voltage	V _{GD}	T _j = 125 °C, V _{DM} = 1/2 V _{DRM}	0.2	-	-	V		
Holding Current	I _H	V _{DM} = 24 V, I _{TM} = 5 A	-	7	-	mA		
Critical Rate of Rise of Off-State Voltage	dV/dt	T _j = 125 °C, V _{DM} = 2/3 V _{DRM}	-	100	-	V/μs		
Commutating dV/dt	(dV/dt) _C	T _j = 125 °C (di _T /dt) _C = -1.6 A/ms V _{DM} = 400 V	5	-	-	V/μs		
Thermal Resistance	R _{th(j-c)}	Junction to Case	-	-	4	°C/W	See Fig. 13	
Thermal Resistance	R _{th(j-a)}	Junction to Ambient*	-	-	62.5	°C/W	AC03DJM-Z AC03FJM-Z	

* Mounted on ceramic substrate of 7.5 cm² × 0.7 mm.

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Fig. 1 $i_T - v_T$ CHARACTERISTIC

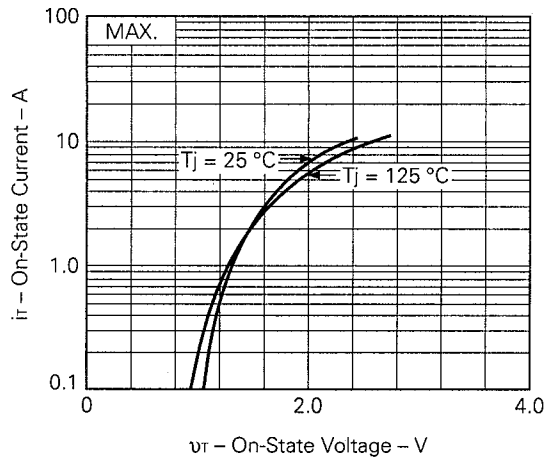


Fig. 2 I_{TSM} RATING

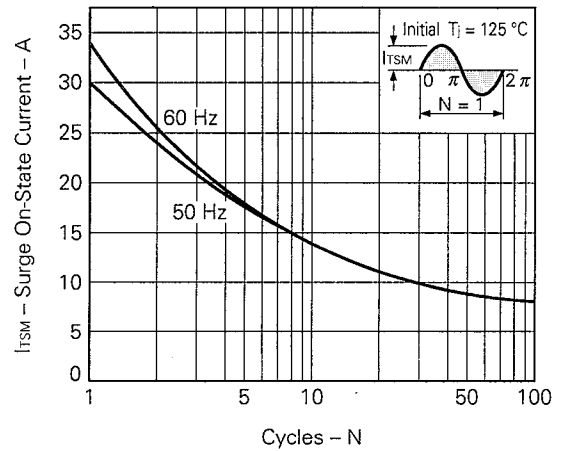


Fig. 3 $V_G - I_G$ RATING

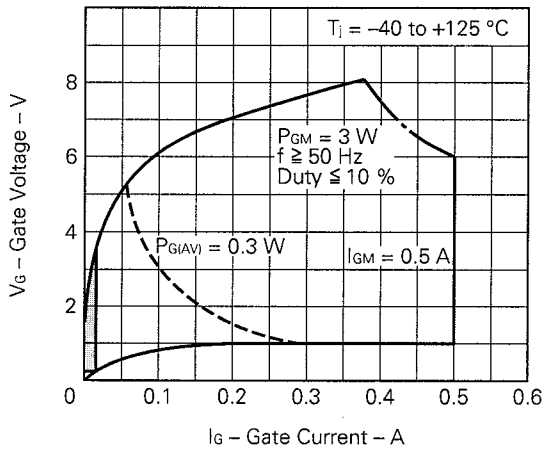


Fig. 4 $V_{GT} - I_{GT}$ CHARACTERISTIC

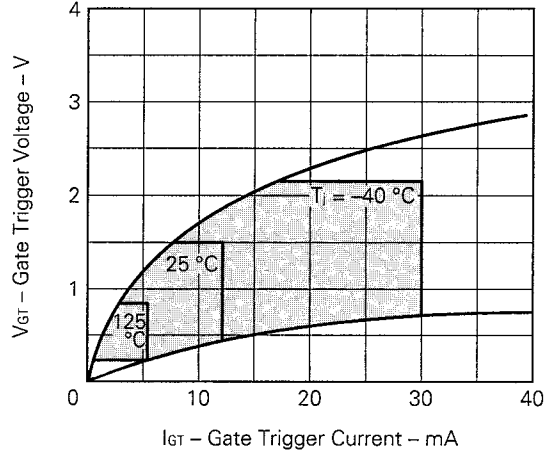


Fig. 5 $I_{GT} - T_a$ TYPICAL DISTRIBUTION

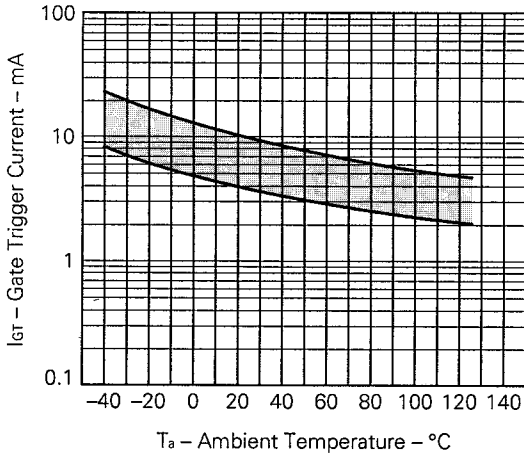


Fig. 6 $V_{GT} - T_a$ TYPICAL DISTRIBUTION

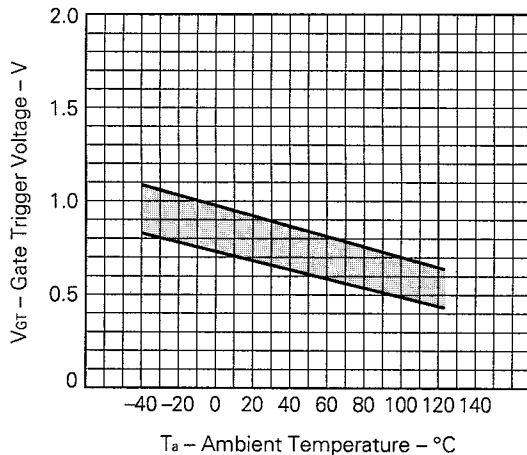


Fig. 7 $i_{GT} - \tau$ TYPICAL DISTRIBUTION

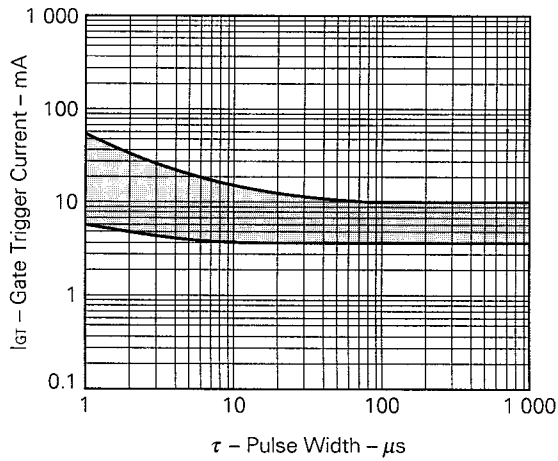


Fig. 8 $v_{GT} - \tau$ TYPICAL DISTRIBUTION

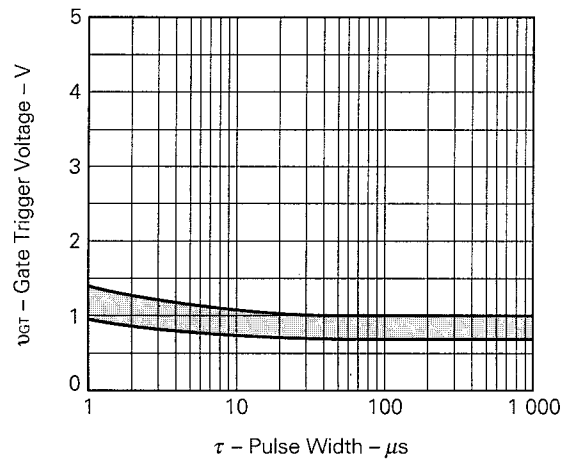


Fig. 9 $I_H - T_a$ TYPICAL DISTRIBUTION

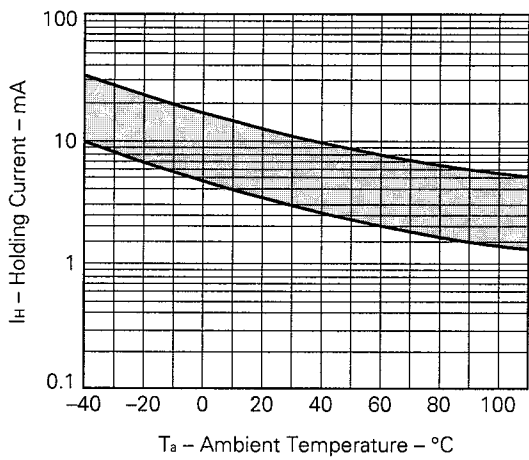


Fig. 10 $P_{T(AV)} - I_{T(RMS)}$ CHARACTERISTIC

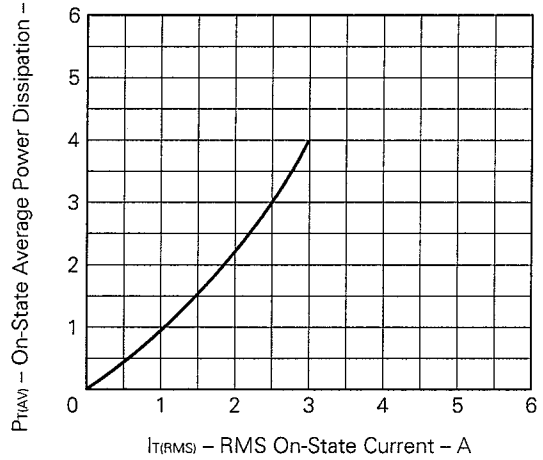


Fig. 11 $T_c - I_{T(RMS)}$ RATING

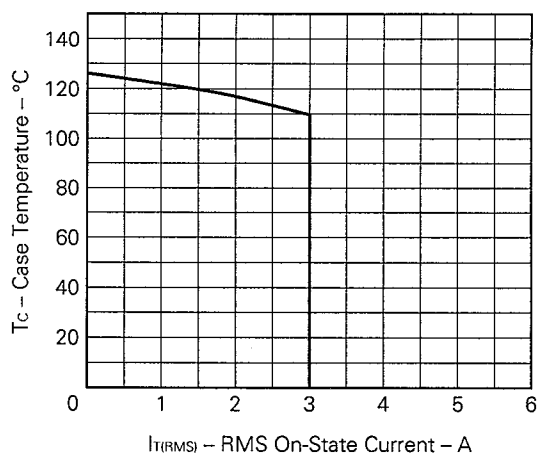


Fig. 12 $T_a - I_{T(RMS)}$ RATING

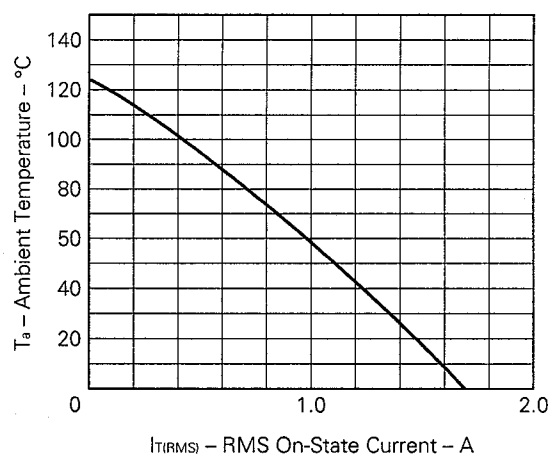
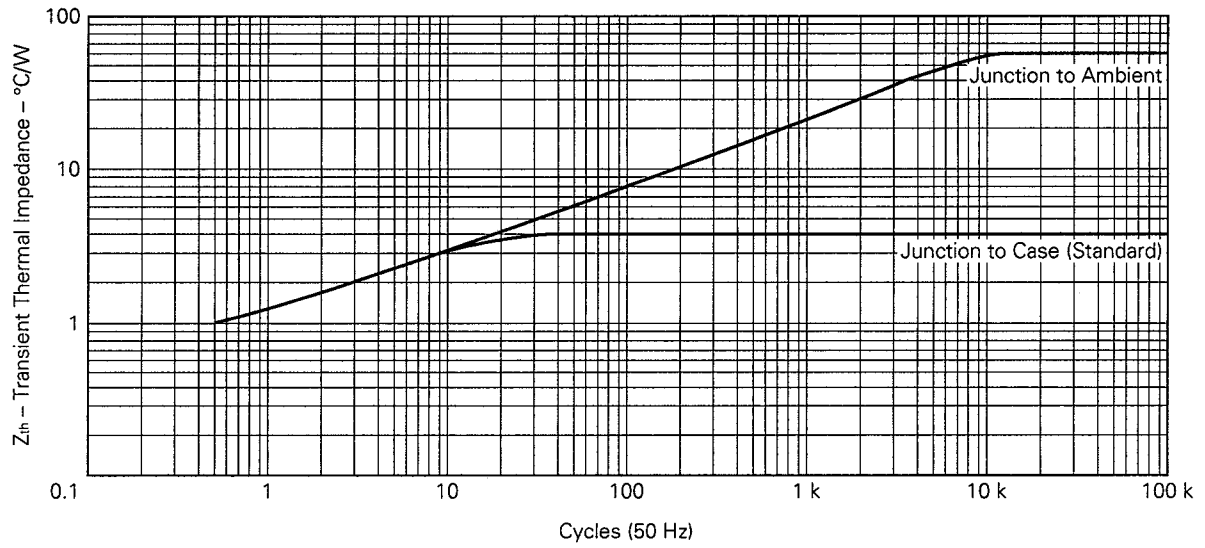


Fig. 13 Z_{th} CHARACTERISTIC



REFERENCE

Document name	Document No.
Quality control guide of semiconductor devices	MEI-1202
Assembly manual of semiconductor devices	IEI-1207

[MEMO]

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.